



Docket: 0756-1400

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

- 1 -

In re Patent Application of)
Shunpei YAMAZAKI et al.)
Serial No. 08/520,079) Art Unit: 2503
Filed: August 28, 1995) Examiner: J. Jackson, Jr.
For: SEMICONDUCTOR CIRCUIT FOR)
ELECTRO-OPTICAL DEVICE AND)
METHOD OF MANUFACTURING)
THE SAME) Date: February 23, 1998

INFORMATION DISCLOSURE STATEMENT AND NOTIFICATION OF RELATED APPLICATIONS

Honorable Assistant Commissioner for Patents Washington, D.C. 20231

Sir:

In accordance with the provisions of 37 C.F.R. 1.56 and 37 C.F.R. 1.97-1.99, it is requested that the references listed on the attached Form PTO-1449 be made of record in the above-identified application.

Copies of the references are submitted herewith in accordance with 37 C.F.R. 1.98(a). These references are owned by the assignee of the instant

- 2 - Docket: 0756-1400

application and relate to the use of crystallization catalysts. U.S. Patent No. 5,543,636 relates to a channel region including oxygen, nitrogen and carbon.

Also, attached hereto is a list of pending applications owned by the assignee of the instant application that relate to a semiconductor circuit including a monodomain region.

Hence, it is requested that the references submitted herewith be considered and made of record in the subject application.

Respectfully submitted,

effred D. Costellia

Registration No. 35,483

Sixbey, Friedman, Leedom & Ferguson, P.C.

2010 Corporate Ridge, Suite 600

McLean, Virginia 22102

(703) 790-9110

- 3 -

Docket: 0756-1400

LIST OF RELATED APPLICATIONS

Serial Number	Filing Date	<u>Title</u>
08/521,533	August 30, 1995	Thin Film Type Monolithic Semiconductor Device
08/525,219	September 8, 1995	Method for Producing Semiconductor Device
08/528,407	September 14, 1995	Method of Fabricating Semiconductor Device
08/604,547	February 21, 1996	
08/769,113	December 18, 1996	Semiconductor Circuit for Electro-Optical Device and Method of Manufacturing the Same
08/802,276	February 19, 1997	
08/802,675	February 19, 1997	
08/803,693	February 24, 1997	
08/805,952	February 24, 1997	
08/865,047	May 29, 1997	Thin Film Type Monolithic Semiconductor Device